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Octal bus transceiver; 3-state Rev. 8 — 28 June 2013

Product data sheet

General description 1.

The 74LVC245A; 74LVCH245A are 8-bit transceivers featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The device features an output enable (OE) input for easy cascading and a send/receive (DIR) input for direction control. OE controls the outputs so that the buses are effectively isolated.

Inputs can be driven from either 3.3 V or 5 V devices. When disabled, up to 5.5 V can be applied to the outputs. These features allow the use of these devices in mixed 3.3 V and 5 V applications.

The 74LVCH245A bus hold on data inputs eliminates the need for external pull-up resistors to hold unused inputs.

2. **Features and benefits**

- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low-power consumption
- Direct interface with TTL levels
- Inputs accept voltages up to 5.5 V
- High-impedance when V_{CC} = 0 V
- Bus hold on all data inputs (74LVCH245A only)
- Complies with JEDEC standard:
 - JESD8-7A (1.65 V to 1.95 V)
 - JESD8-5A (2.3 V to 2.7 V)
 - JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115B exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

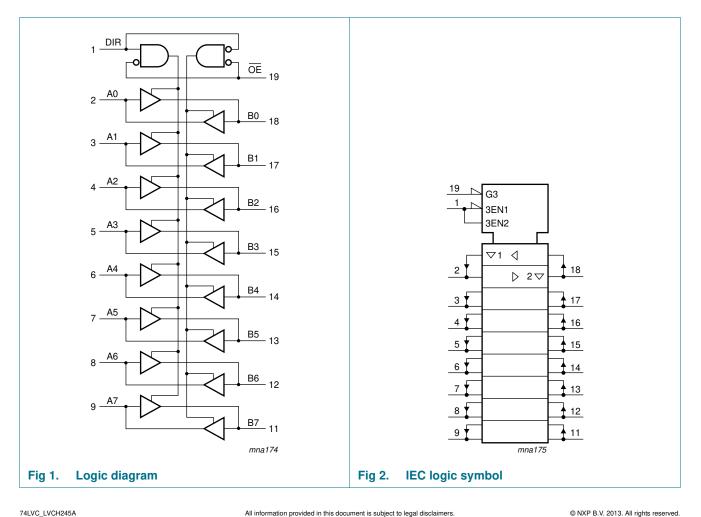


Octal bus transceiver; 3-state

Ordering information 3.

Type number	Package								
	Temperature range	Name	Description	Version					
74LVC245AD	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads;	SOT163-1					
74LVCH245AD			body width 7.5 mm						
74LVC245ADB			plastic shrink small outline package; 20 leads;	SOT339-1					
74LVCH245ADB			body width 5.3 mm						
74LVC245APW	–40 °C to +125 °C			SOT360-1					
74LVCH245APW			body width 4.4 mm						
74LVC245ABQ	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced	SOT764-1					
74LVCH245ABQ			very thin quad flat package; no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm						
74LVC245ABX	–40 °C to +125 °C	DHXQFN20	plastic dual in-line compatible thermal enhanced	SOT1045-2					
74LVCH245ABX		extremely thin quad flat package; no leads; 20 terminals; body $4.5 \times 2.5 \times 0.5$ mm							

Functional diagram 4.



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Octal bus transceiver; 3-state

5. Pinning information

74LVC245A 74LVCH245A ۲ در terminal 1 DIR index area 2 L-J 74LVC245A 2) (19 ŌĒ 74LVCH245A A0 3) (18 B0 A1 DIR 1 20 V_{CC} (17 A2 4 B1 A0 2 19 OE (16 5) B2 A3 18 B0 A1 3 (15 A2 4 17 B1 A4 6) В3 A3 5 16 B2 7) (14 A5 Β4 15 B3 A4 6 8) GND⁽¹⁾ (13 B5 A6 14 B4 A5 7 A7 9) (12 B6 A6 8 13 B5 P Ē 12 B6 A7 9 GND B7 001aak293 GND 10 11 B7 Transparent top view 001aak292 (1) This is not a supply pin. The substrate is attached to this pad using conductive die attach material. There is no electrical or mechanical requirement to solder this pad. However, if it is soldered, the solder land should remain floating or be connected to GND. Fig 3. Pin configuration for SO20 and (T)SSOP20 Fig 4. Pin configuration for DHVQFN20 and DHXQFN20

5.1 Pinning

5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
DIR	1	direction control
A0 to A7	2, 3, 4, 5, 6, 7, 8, 9	data input/output
GND	10	ground (0 V)
B0 to B7	18, 17, 16, 15, 14, 13, 12, 11	data input/output
OE	19	output enable input (active LOW)
V _{CC}	20	supply voltage

6. Functional description

Table 3.	Function selection ^[1]						
Inputs		Inputs/outputs	Inputs/outputs				
OE	DIR	An	Bn				
L	L	An = Bn	inputs				
L	Н	inputs	Bn = An				
Н	Х	Z	Z				

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high impedance OFF-state.

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
Ι _{ΟΚ}	output clamping current	$V_{O} > V_{CC}$ or $V_{O} < 0$ V	-	±50	mA
Vo	output voltage	output HIGH or LOW	[2] -0.5	$V_{CC} + 0.5$	V
		output 3-state	[2] -0.5	+6.5	V
lo	output current	$V_{O} = 0 V$ to V_{CC}	-	±50	mA
I _{CC}	supply current		-	100	mA
I _{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$	<u>[3]</u>	500	mW

[1] The minimum input voltage ratings may be exceeded if the input current ratings are observed.

[2] The output voltage ratings may be exceeded if the output current ratings are observed.

[3] For SO20 packages: above 70 °C derate linearly with 8 mW/K.
 For (T)SSOP20 packages: above 60 °C derate linearly with 5.5 mW/K.
 For DHVQFN20 and DHXQFN20 packages: above 60 °C derate linearly with 4.5 mW/K.

Octal bus transceiver; 3-state

8. Recommended operating conditions

Table 5.	Recommended operating conditi	ons				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.65	-	3.6	V
		functional	1.2	-	3.6	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	output HIGH or LOW	0	-	V _{CC}	V
		output 3-state	0	-	5.5	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.2 V to 2.7 V	0	-	20	ns/V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	0	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	35 °C	–40 °C to	o +125 ℃	Unit
				Typ[1]	Max	Min	Max	1
V _{IH}	HIGH-level	V _{CC} = 1.2 V	1.08	-	-	1.08	-	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	-	-	$0.65 \times V_{CC}$	-	V
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
V _{IL}	LOW-level	V _{CC} = 1.2 V	-	-	0.12	-	0.12	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	-	$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$	-	-	0.7	-	0.7	V
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.8	-	0.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$						
		$I_{O} = -100 \ \mu A;$ $V_{CC} = 1.65 \ V \text{ to } 3.6 \ V$	$V_{CC}-0.2$	-	-	$V_{CC}-0.3$	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	1.05	-	V
		I_{O} = -8 mA; V_{CC} = 2.3 V	1.8	-	-	1.65	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	2.05	-	V
		$I_{O} = -18 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	-	-	2.25	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.2	-	-	2.0	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	output voltage	I _O = 100 μA; V _{CC} = 1.65 V to 3.6 V	-	-	0.2	-	0.3	V
		$I_{O} = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	-	0.65	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.6	-	0.8	V
		I_{O} = 12 mA; V_{CC} = 2.7 V	-	-	0.4	-	0.6	V
		$I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.8	V
I _I	input leakage current	V _I = 5.5 V or GND; [2] V _{CC} = 3.6 V	-	±0.1	±5	-	±20	μA

Octal bus transceiver; 3-state

Symbol	Parameter	Conditions		-40) °C to +85	5 °C	–40 °C to	o +125 ℃	Unit
				Min	Typ[1]	Max	Min	Max	
l _{oz}	OFF-state output current	$ \begin{array}{l} V_{I} = V_{IH} \text{ or } V_{IL}; \\ V_{O} = 5.5 \text{ V or GND}; \\ V_{CC} = 3.6 \text{ V} \end{array} $	<u>[3]</u>	-	±0.1	±5	-	±20	μA
Ioff	power-off leakage current	$V_{I} \text{ or } V_{O}$ = 5.5 V; V_{CC} = 0.0 V		-	±0.1	±10	-	±20	μA
I _{CC}	supply current			-	0.1	10	-	40	μ A
∆I _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$		-	5	500	-	5000	μA
Cı	input capacitance			-	4.0	-	-	-	pF
C _{I/O}	input/output capacitance			-	10	-	-	-	pF
I _{BHL}	bus hold	$V_{CC} = 1.65; V_1 = 0.58 V$	[4][5]	10	-	-	10	-	μA
	LOW current	$V_{CC} = 2.3; V_I = 0.7 V$		30	-	-	25	-	μA
		$V_{CC} = 3.0; V_I = 0.8 V$		75	-	-	60	-	μA
I _{BHH}	bus hold	$V_{CC} = 1.65; V_I = 1.07 V$	[4][5]	-10	-	-	-10	-	μA
	HIGH current	$V_{CC} = 2.3; V_I = 1.7 V$		-30	-	-	-25	-	μA
		$V_{CC} = 3.0; V_I = 2.0 V$		-75	-	-	-60	-	μA
I _{BHLO}	bus hold	V _{CC} = 1.95 V		200	-	-	200	-	μA
	LOW overdrive	V _{CC} = 2.7 V		300	-	-	300	-	μA
	current	V _{CC} = 3.6 V	[4][6]	500	-	-	500	-	μA
I _{BHHO}	bus hold	V _{CC} = 1.95 V		-200	-	-	-200	-	μA
	HIGH	V _{CC} = 2.7 V		-300	-	-	-300	-	μA
	overdrive current	V _{CC} = 3.6 V	[4][6]	-500	-	-	-500	-	μA

Table 6. Static characteristics ... continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

[2] The bus hold circuit is switched off when $V_{\rm I}$ > $V_{\rm CC}$ allowing 5.5 V on the input terminal.

[3] For I/O ports the parameter I_{OZ} includes the input leakage current.

[4] Valid for data inputs of bus hold parts only (74LVCH245A). Note that control inputs do not have a bus hold circuit.

[5] The specified sustaining current at the data input holds the input below the specified V₁ level.

[6] The specified overdrive current at the data input forces the data input to the opposite input state.

Octal bus transceiver; 3-state

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 7.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	–40 °C to	o +125 ℃	Unit
		-		Min	Typ ^[2]	Max	Min	Max	-
t _{pd}	propagation	nAn to nBn; nBn to nAn; see Figure 5	[1]						
	delay	V _{CC} = 1.2 V		-	17.0	-	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		1.5	6.5	14.6	1.5	16.9	ns
		V_{CC} = 2.3 V to 2.7 V		1.0	3.4	7.6	1.0	8.7	ns
		$V_{CC} = 2.7 V$		1.5	3.4	7.3	1.5	9.5	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.5	2.9	6.3	1.5	8.0	ns
t _{en}	enable time	nOE to nAn, nBn; see <u>Figure 6</u>	[1]						
		$V_{CC} = 1.2 V$		-	22.0	-	-	-	ns
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		1.9	8.3	19.5	1.9	22.5	ns
		V_{CC} = 2.3 V to 2.7 V		1.5	4.6	10.7	1.5	12.4	ns
		$V_{CC} = 2.7 V$		1.5	4.8	9.5	1.5	12.0	ns
		$V_{CC} = 3.0 V \text{ to } 3.6 V$		1.5	3.7	8.5	1.5	11.0	ns
t _{dis}	disable time	nOE to nAn, nBn; see <u>Figure 6</u>	[1]						
		$V_{CC} = 1.2 V$		-	12.0	-	-	-	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.9	5.5	12.3	2.9	14.2	ns
		V_{CC} = 2.3 V to 2.7 V		1.0	3.1	7.1	1.0	8.2	ns
		$V_{CC} = 2.7 V$		1.5	3.9	8.0	1.5	10.0	ns
		$V_{CC} = 3.0 V \text{ to } 3.6 V$		1.7	3.6	7.0	1.7	9.0	ns
t _{sk(o)}	output skew time		[3]	-	-	1.0	-	1.5	ns
C _{PD}	power	per input; $V_1 = GND$ to V_{CC}	[4]						
	dissipation capacitance	$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		-	7.7	-	-	-	pF
	capacitance	$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		-	11.3	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V		-	14.4	-	-	-	pF

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

 t_{en} is the same as t_{PZL} and t_{PZH} .

 t_{dis} is the same as t_{PLZ} and $t_{\text{PHZ}}.$

[2] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.2 V, 1.8 V, 2.5 V, 2.7 V and 3.3 V respectively.

[3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz; f_o = output frequency in MHz

 C_L = output load capacitance in pF

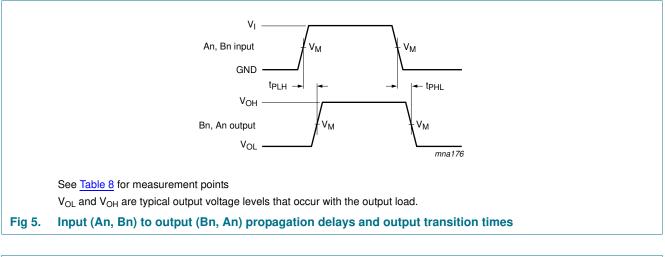
 V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}{}^2 \times f_{o})$ = sum of the outputs.

Octal bus transceiver; 3-state

11. AC waveforms



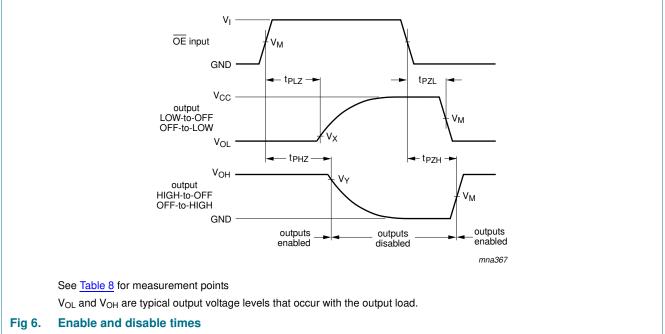


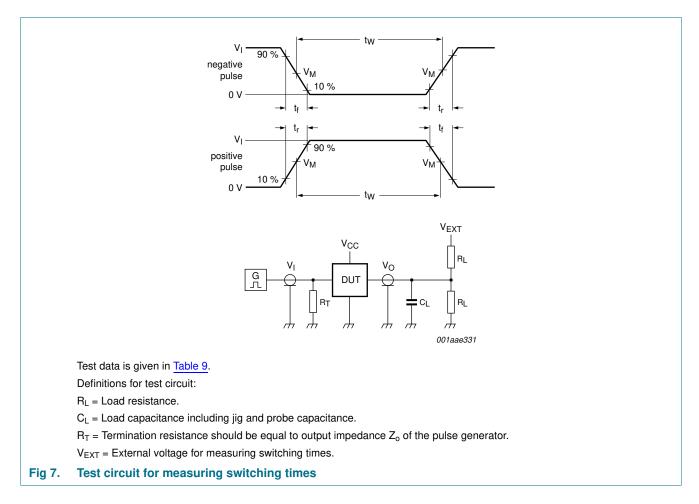
Table 8.Measurement points

VM	Input	Input					
	VI	$t_r = t_f$	V _X	V _Y			
$0.5\times V_{CC}$	V _{CC}	\leq 2.5 ns	V _{OL} + 0.15 V	V _{OH} – 0.15 V			
$0.5\times V_{CC}$	V _{CC}	\leq 2.5 ns	V _{OL} + 0.15 V	V _{OH} – 0.15 V			
$0.5\times V_{CC}$	V _{CC}	\leq 2.5 ns	V _{OL} + 0.15 V	V _{OH} – 0.15 V			
1.5 V	2.7 V	\leq 2.5 ns	V _{OL} + 0.3 V	$V_{OH} - 0.3 \ V$			
1.5 V	2.7 V	\leq 2.5 ns	V _{OL} + 0.3 V	$V_{OH} - 0.3 \ V$			
	$0.5 \times V_{CC} \\ 0.5 \times V_{CC} \\ 0.5 \times V_{CC} \\ 1.5 V$	V_I $0.5 \times V_{CC}$ V_{CC} $0.5 \times V_{CC}$ V_{CC} $0.5 \times V_{CC}$ V_{CC} $1.5 V$ $2.7 V$	VI $t_r = t_f$ $0.5 \times V_{CC}$ V_{CC} $\leq 2.5 \text{ ns}$ 1.5 V 2.7 V $\leq 2.5 \text{ ns}$	$\begin{tabular}{ c c c c } \hline V_{I} & $t_{r} = t_{f}$ & V_{X} \\ \hline $0.5 \times V_{CC}$ & V_{CC} & ≤ 2.5 ns & $V_{OL} + 0.15$ V$ \\ \hline $0.5 \times V_{CC}$ & V_{CC} & ≤ 2.5 ns & $V_{OL} + 0.15$ V$ \\ \hline $0.5 \times V_{CC}$ & V_{CC} & ≤ 2.5 ns & $V_{OL} + 0.15$ V$ \\ \hline 1.5 V$ & 2.7 V$ & ≤ 2.5 ns & $V_{OL} + 0.3$ V$ \\ \hline \end{tabular}$			

NXP Semiconductors

74LVC245A; 74LVCH245A

Octal bus transceiver; 3-state



1	Supply v	altana	Input	
1	Table 9.	Test data		

Supply voltage	Input		Load	Load		V _{EXT}		
	VI	t _r , t _f	CL	RL	t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PHZ} , t _{PZH}	
1.2 V	V _{CC}	\leq 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND	
1.65 V to 1.95 V	V _{CC}	\leq 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND	
2.3 V to 2.7 V	V _{CC}	\leq 2 ns	30 pF	500 Ω	open	$2\times V_{CC}$	GND	
2.7 V	2.7 V	\leq 2.5 ns	50 pF	500 Ω	open	$2\times V_{CC}$	GND	
3.0 V to 3.6 V	2.7 V	\leq 2.5 ns	50 pF	500 Ω	open	$2\times V_{CC}$	GND	

Octal bus transceiver; 3-state

12. Package outline

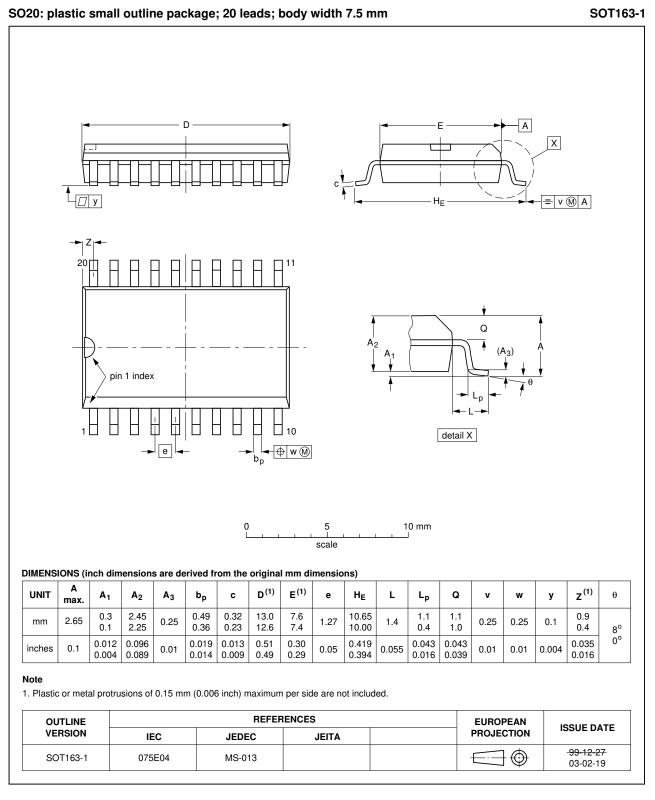


Fig 8. Package outline SOT163-1 (SO20)

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Octal bus transceiver; 3-state

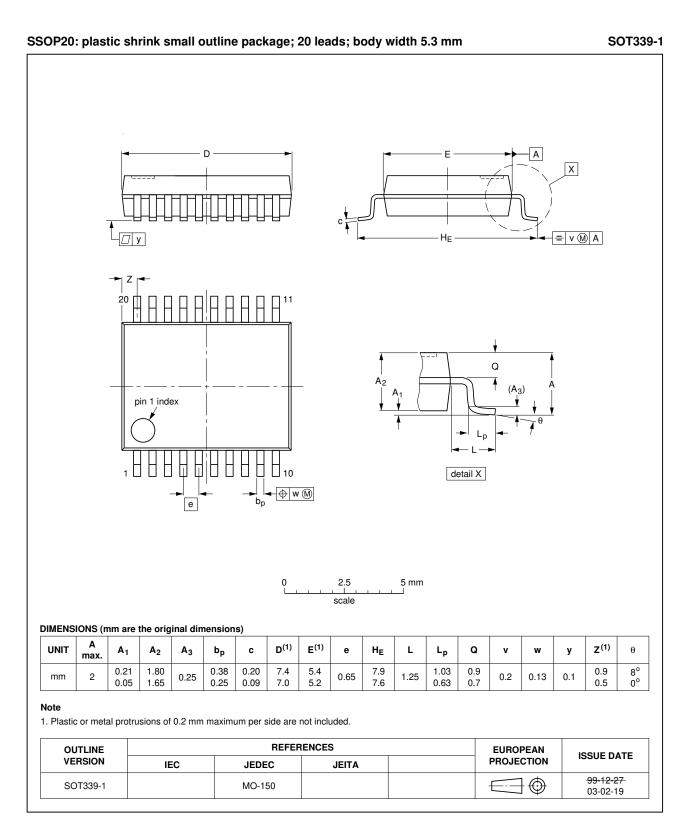


Fig 9. Package outline SOT339-1 (SSOP20)

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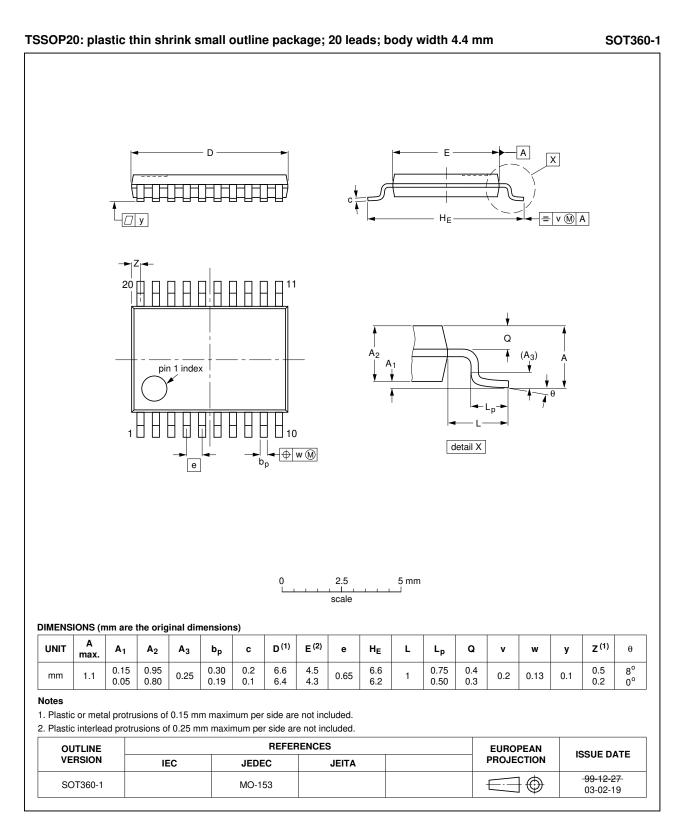
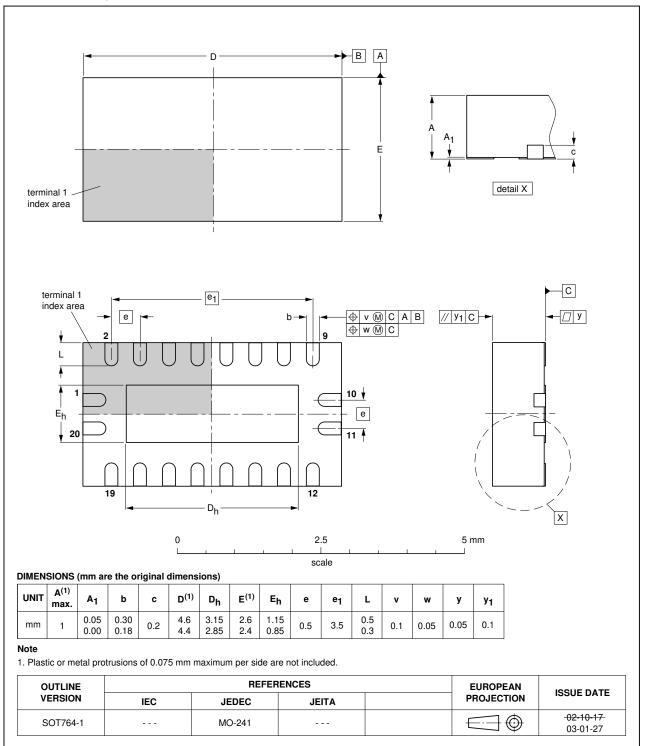


Fig 10. Package outline SOT360-1 (TSSOP20)

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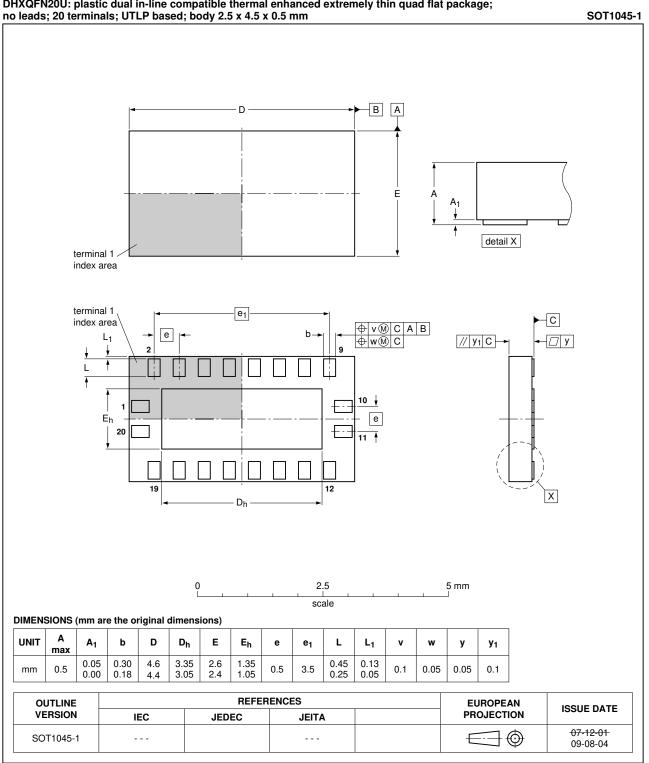


DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

Fig 11. Package outline SOT764-1 (DHVQFN20)

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Octal bus transceiver; 3-state



DHXQFN20U: plastic dual in-line compatible thermal enhanced extremely thin quad flat package;

74LVC_LVCH245A Product data sheet

Fig 12. Package outline SOT1045-2 (DHXQFN20)



Octal bus transceiver; 3-state

13. Abbreviations

Table 10.	Abbreviations
Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC_LVCH245A v.8	20130628	Product data sheet	-	74LVC_LVCH245A v.7
Modifications:		umbers 74LVC245ABX a jed to DHXQFN20 (SOT		(DHXQFN20U (SOT1045-1)
74LVC_LVCH245A v.7	20120405	Product data sheet	-	74LVC_LVCH245A v.6
Modifications:	Table note	e 4 of Table 6: corrected (errata)	
74LVC_LVCH245A v.6	20111125	Product data sheet	-	74LVC_LVCH245A v.5
Modifications:	• <u>Table 4, Table 4</u>	able 5, <u>Table 6</u> , <u>Table 7</u> , a	and <u>Table 9</u> : values a	added for lower voltage ranges.
74LVC_LVCH245A v.5	20090825	Product data sheet	-	74LVC_LVCH245A v.4
74LVC_LVCH245A v.4	20090703	Product data sheet	-	74LVC_LVCH245A v.3
74LVC_LVCH245A v.3	20030507	Product specification	-	74LVC245A_74LVCH245A v.2
74LVC245A_74LVCH245A v.2	20020620	Product specification	-	74LVC245A_74LVCH245A v.1
74LVC245A_74LVCH245A v.1	19971219	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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